

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MBL6353SFT, TC7MBL6353SFK, TC7MBL6353SFTG

Low Voltage/Low Capacitance Dual 1-of-2 Multiplexer/Demultiplexer

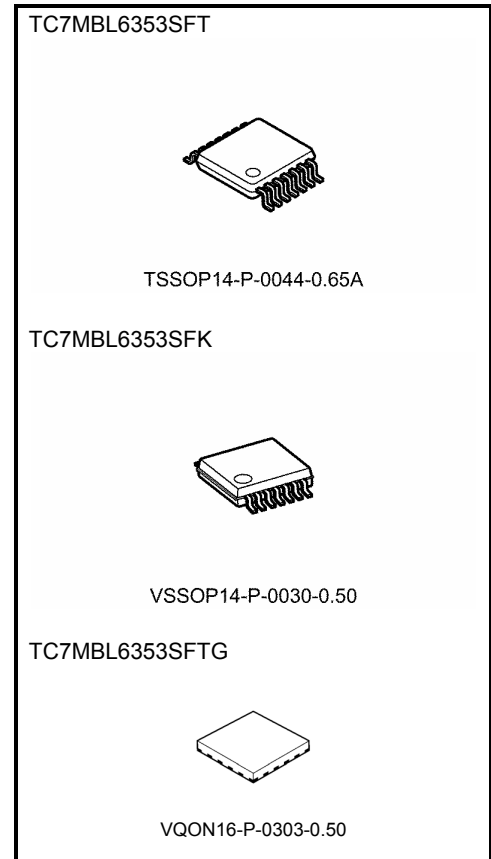
The TC7MBL6353S is a Low Voltage/Low Capacitance CMOS Dual 1-of-2 Multiplexer/Demultiplexer. The low on-resistance of the switch allows connections to be made with minimal propagation delay time.

This device consists of two individual two-inputs multiplexer/demultiplexer with common select input (S) and output enable (\overline{OE}). The A input is connected to the B1 or B2 outputs as determined by the combination of both the select input (S) and output enable (\overline{OE}). When the output enable (\overline{OE}) input is held at "H" level, the switches are open regardless of the state of the select inputs, and a high-impedance state exists between the switches.

All inputs are equipped with protection circuits against static discharge.

Features

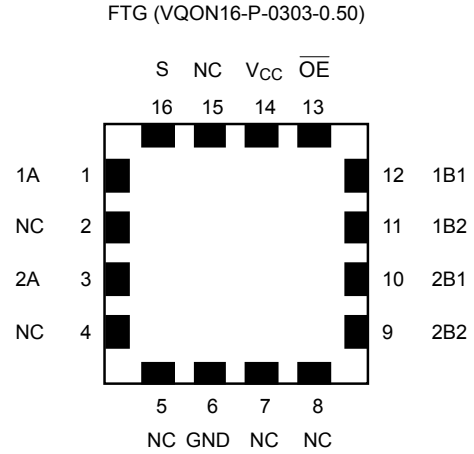
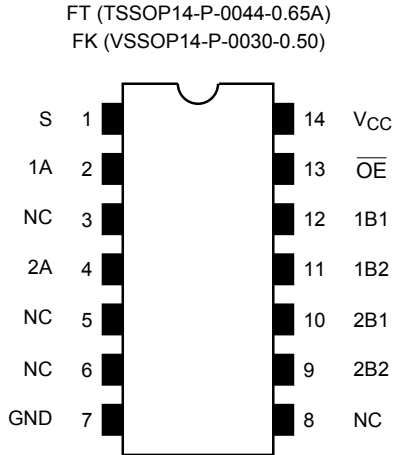
- Operating voltage: $V_{CC} = 1.65 \sim 3.6 \text{ V}$
- Low capacitance: $C_{I/O} = 15 \text{ pF}$ Switch On (typ.) @3 V
- Low on-resistance: $R_{ON} = 9 \Omega$ (typ.) @3 V
- ESD performance: Machine model $\geq \pm 200 \text{ V}$
Human body model $\geq \pm 2000 \text{ V}$
- Power-down protection for inputs (\overline{OE} input only)
- Package: TSSOP14, VSSOP (US14), VQON16



Weight	
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)
VSSOP14-P-0030-0.50	: 0.02 g (typ.)
VQON16-P-0303-0.50	: 0.013 g (typ.)

Note: When mounting VQON package, the type of recommended flux is RA or RMA.

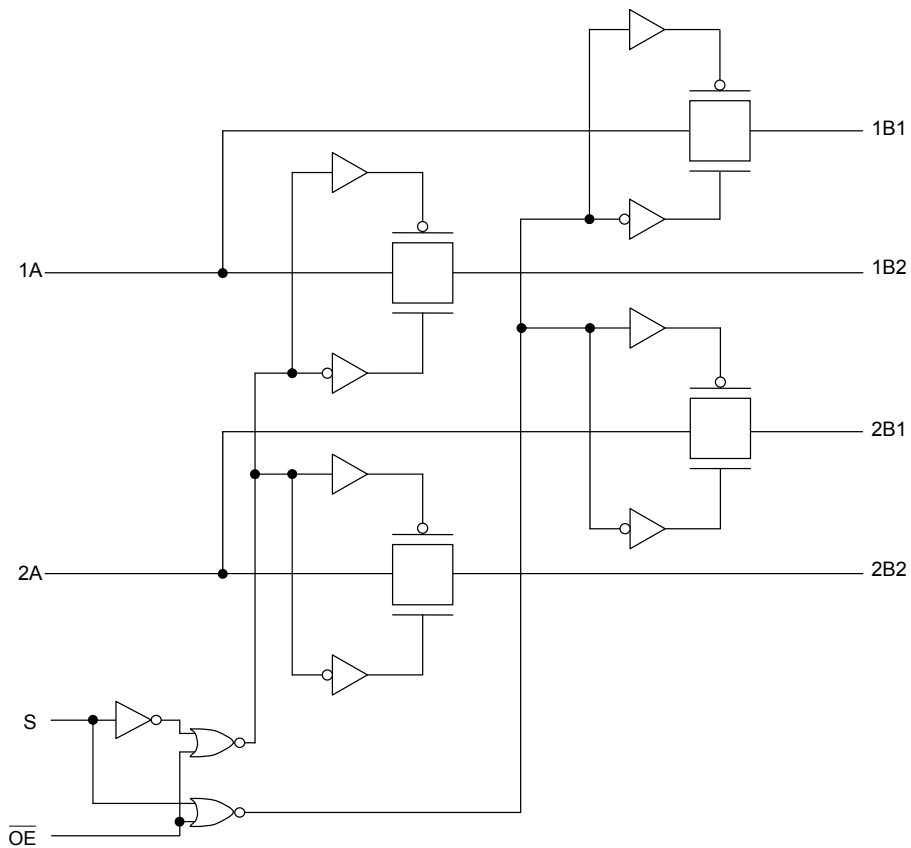
Pin Assignment (top view)



Truth Table

Inputs		Function
S	\overline{OE}	
X	H	Disconnect
L	L	nA port = nB1 port
H	L	nA port = nB2 port

System Diagram



Absolute Maximum Ratings (Note)

Characteristic	Symbol	Rating	Unit	
Power supply range	V_{CC}	-0.5~4.6	V	
Control pin input voltage	V_{IN}	-0.5~4.6	V	
Switch terminal I/O voltage	V_S	-0.5~ $V_{CC} + 0.5$	V	
Clump diode current	Control input pin	I_{IK}	-50	mA
	Switch terminal		±50	mA
Switch I/O current	I_S	50	mA	
Power dissipation	P_D	180	mW	
DC V_{CC} /GND current	I_{CC}/I_{GND}	±100	mA	
Storage temperature	T_{stg}	-65~150	°C	

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristic	Symbol	Rating	Unit
Power supply voltage	V_{CC}	1.65~3.6	V
Control pin input voltage	V_{IN}	0~3.6	V
Switch I/O voltage	V_S	0~ V_{CC}	V
Operating temperature	T_{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics (Ta = -40~85°C)

Parameter	Symbol	Test Condition	V _{CC} (V)	Min	Typ.	Max	Unit
Input voltage	"H" level	V _{IH}	—	1.65~3.6	0.7 × V _{CC}	—	V
	"L" level	V _{IL}	—	1.65~3.6	—	0.3 × V _{CC}	
Input leakage current (\overline{OE} , S)	I _{IN}	V _{IN} = 0~3.6V	1.65~3.6	—	—	±1.0	μA
Power-off leakage current	I _{OFF}	\overline{OE} = 0~3.6 V	0	—	—	1.0	μA
Off-state leakage current (switch off)	I _{SZ}	A, B = 0~V _{CC} , \overline{OE} = V _{CC}	1.65~3.6	—	—	±1.0	μA
On resistance (Note2)	R _{ON}	V _{IS} = 0 V, I _{IS} = 30 mA (Note1)	3.0	—	9	13	Ω
		V _{IS} = 3.0 V, I _{IS} = 30 mA (Note1)	3.0	—	15	20	
		V _{IS} = 2.4 V, I _{IS} = 15 mA (Note1)	3.0	—	19	27	
		V _{IS} = 0 V, I _{IS} = 24 mA (Note1)	2.3	—	10	16	
		V _{IS} = 2.3 V, I _{IS} = 24 mA (Note1)	2.3	—	17	24	
		V _{IS} = 2.0 V, I _{IS} = 15 mA (Note1)	2.3	—	21	30	
Increase in I _{CC} per input	I _{CC}	V _{IN} = V _{CC} or GND, I _{OUT} = 0	3.6	—	—	10	μA

Note1: All typical values are at Ta=25°C.

Note2: Measured by the voltage drop between A and B pins at the indicated current through the switch.
On resistance is determined by the lower of the voltages on the two (A or B) pins.

AC Characteristics (Ta = -40~85°C)

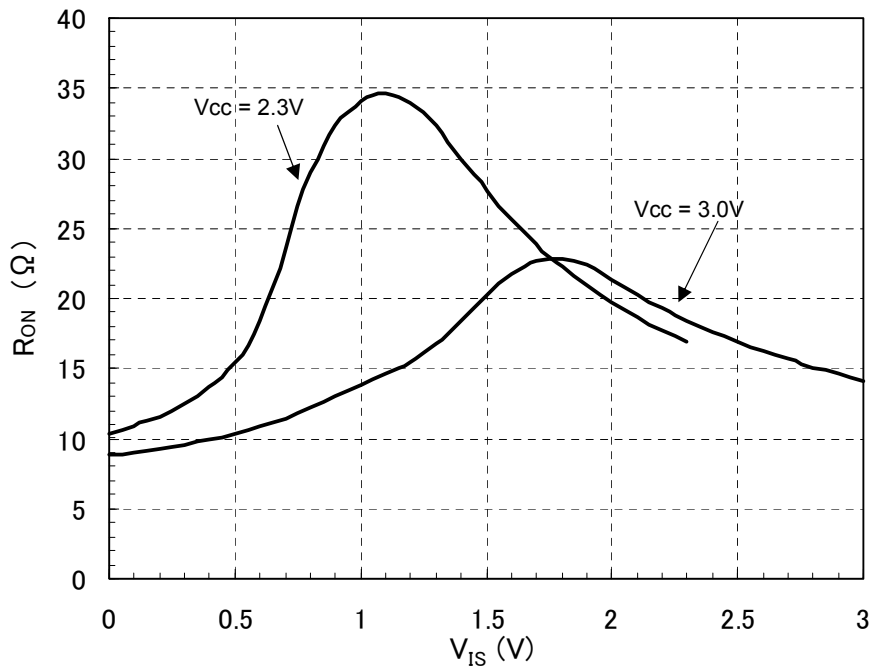
Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time (S to bus)	t _{pLH} t _{pHL}	Figure 1, Figure 2	3.3 ± 0.3	—	6	ns
			2.5 ± 0.2	—	7	
			1.8 ± 0.15	—	11	
Output enable time (\overline{OE} to bus)	t _{pZL} t _{pZH}	Figure 1, Figure 3	3.3 ± 0.3	—	6	ns
			2.5 ± 0.2	—	7	
			1.8 ± 0.15	—	11	
Output enable time (S to bus)	t _{pZL} t _{pZH}	Figure 1, Figure 3	3.3 ± 0.3	—	6	ns
			2.5 ± 0.2	—	7	
			1.8 ± 0.15	—	11	
Output disable time (\overline{OE} to bus)	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	3.3 ± 0.3	—	6	ns
			2.5 ± 0.2	—	7	
			1.8 ± 0.15	—	11	
Output disable time (S to bus)	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	3.3 ± 0.3	—	6	ns
			2.5 ± 0.2	—	7	
			1.8 ± 0.15	—	11	

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Typ.	Unit
Control pin input capacitance (\overline{OE} , S)	C _{IN}		3.0	3	pF
Switch terminal capacitance (B1~2)	C _{I/O}	$\overline{OE} = V_{CC}$ (switch off)	3.0	6	pF
Switch terminal capacitance (A)	C _{I/O}	$\overline{OE} = V_{CC}$ (switch off)	3.0	9	pF
Switch terminal capacitance	C _{I/O}	$\overline{OE} = GND$ (switch on)	3.0	15	pF

Note: This parameter is guaranteed by design

• R_{ON} Characteristic (typ.) Ta=25°C



AC Test Circuit

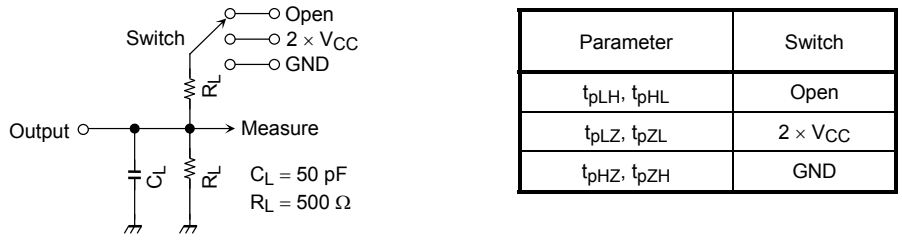


Figure 1

AC Waveform

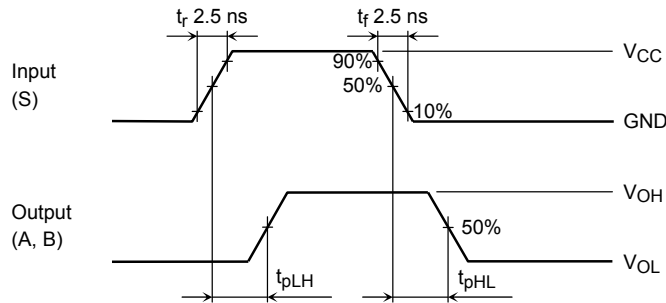


Figure 2 t_{pLH} , t_{pHL}

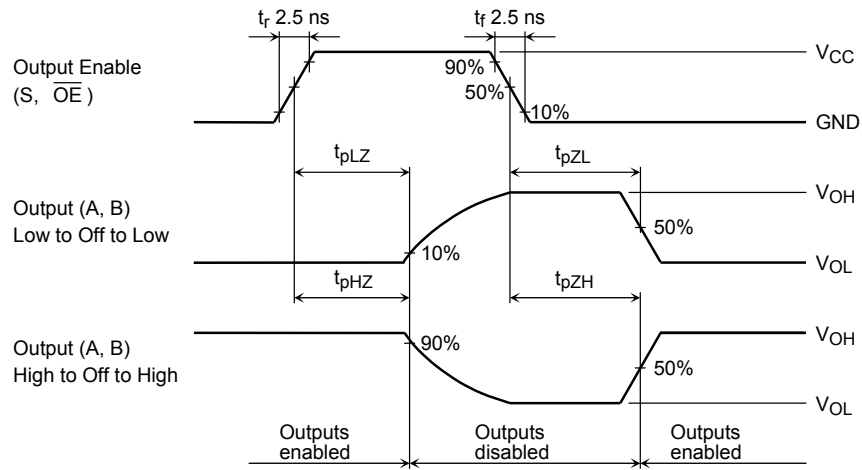


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Rise and Fall Times (tr / tf) of the TC7MBL6353S I/O Signals

The tr(out) and tf(out) values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance (C_{I/O}) and the on-resistance (R_{ON}) of the input.

In practice, the tr(out) and tf(out) values are also affected by the circuit's capacitance and resistance components other than those of the TC7MBL6353S.

The tr / tf (out) values can be approximated as follows. (Figure 4 shows the test circuit.)

$$tr / tf \text{ out (approx)} = - (C_{I/O} + C_L) \cdot (R_{DRIVE} + R_{ON}) \cdot \ln (((V_{OH} - V_{OL}) - V_M) / (V_{OH} - V_{OL}))$$

where, R_{DRIVE} is the output impedance of the previous-stage circuit.

Calculation example:

$$tr \text{ out (approx)} = - (15 + 15) E-12 \cdot (120 + 9) \cdot \ln (((3.0 - 0) - 1.5) / (3.0 - 0))$$

$$\approx 2.7 \text{ ns}$$

Calculation conditions:

V_{CC} = 3.0V , C_L = 15pF , R_{DRIVE} = 120Ω(output impedance of the previous IC), V_M = 1.5V (V_{CC} / 2)

Output of the previous IC = digital (i.e., high-level voltage = V_{CC}; low-level voltage = GND)

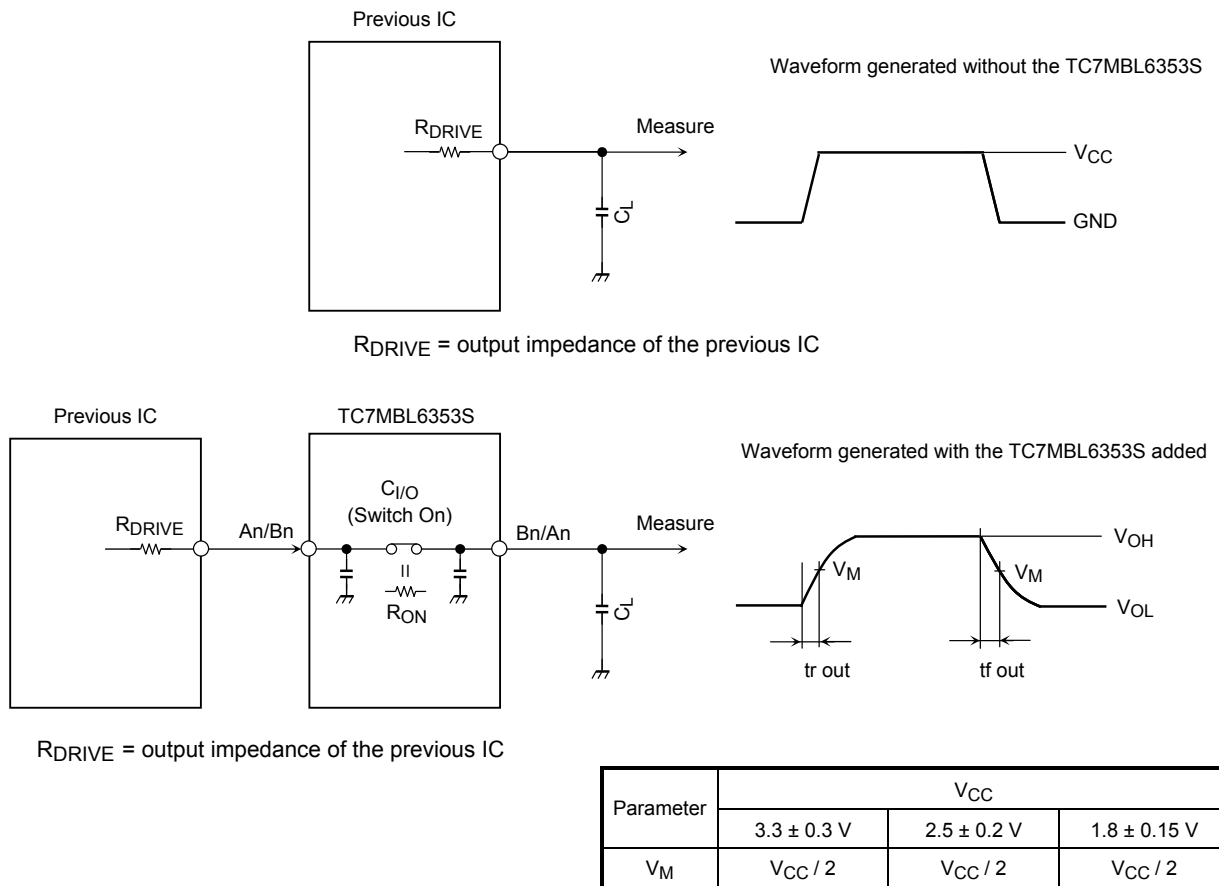
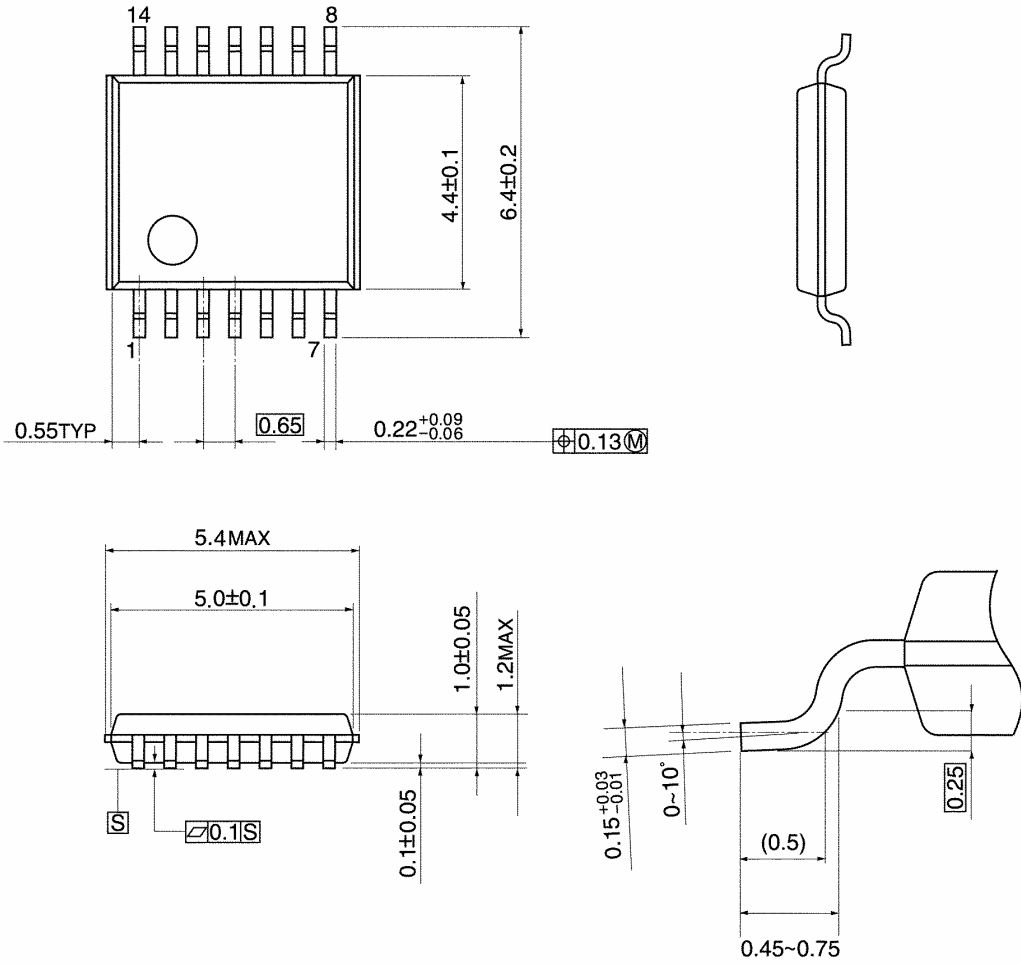


Figure 4 Test Circuit

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm

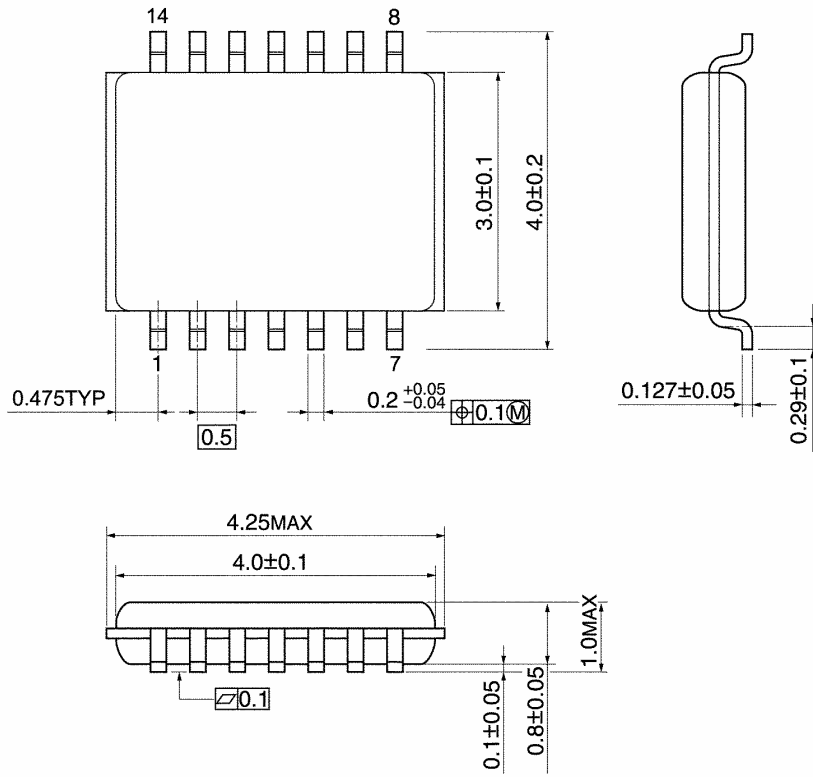


Weight: 0.06 g (typ.)

Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm

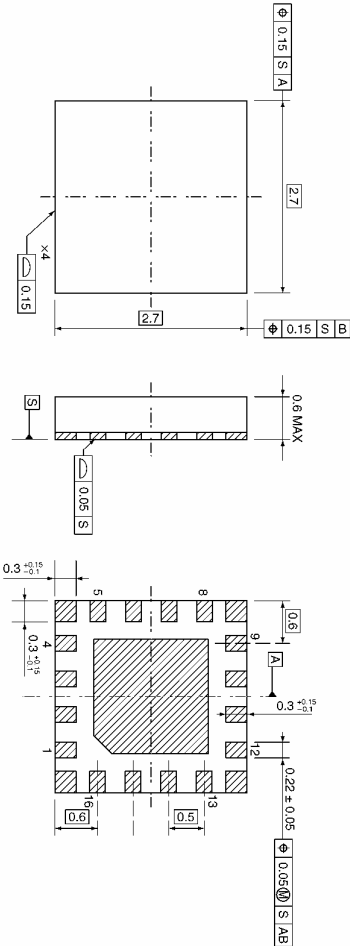


Weight: 0.02 g (typ.)

Package Dimensions

VQON16-P-0303-0.50

Unit: mm



Weight: 0.013 g (typ.)

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20070701-EN GENERAL

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